NCE P-Channel Super Trench Power MOSFET

Description

The NCEP15P30A uses **Super Trench** technology that is uniquely optimized to provide the most efficient high frequency switching performance. Both conduction and switching power losses are minimized due to an extremely low combination of $R_{\text{DS(ON)}}$ and Q_g . This device is ideal for high-frequency switching and synchronous rectification

Application

- DC/DC Converter
- Ideal for high-frequency switching and synchronous rectification

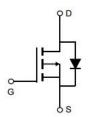
General Features

- V_{DS} =-150V, I_{D} =-30A $R_{DS(ON)}$ =83mΩ (typical) @ V_{GS} =-10V $R_{DS(ON)}$ =92mΩ (typical) @ V_{GS} =-4.5V
- Excellent gate charge x R_{DS(on)} product(FOM)
- Very low on-resistance R_{DS(on)}
- 175 °C operating temperature
- Pb-free lead plating

100% UIS TESTED! 100% ΔVds TESTED!







Schematic Diagram

Package Marking and Ordering Information

Device Marking	Device	Device Package	Reel Size	Tape width	Quantity
NCEP15P30A	NCEP15P30A	TO-220-3L	-	-	-

Absolute Maximum Ratings (T_c=25℃unless otherwise noted)

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	V _{DS}	-150	V
Gate-Source Voltage	V _G s	±20	V
Drain Current-Continuous	I _D	-30	А
Drain Current-Continuous(T _C =100 ℃)	I _D (100℃)	-21	А
Pulsed Drain Current	I _{DM}	-120	А
Maximum Power Dissipation	P _D	230	W
Derating factor		1.53	W/°C
Single pulse avalanche energy (Note 1)	E _{AS}	670	mJ
Operating Junction and Storage Temperature Range	T_{J}, T_{STG}	-55 To 175	$^{\circ}$

Thermal Characteristic

Thermal Resistance, Junction-to-Case	R _{e,JC}	0.65	°C/W
Thermal Resistance, canonic to case	1.000	0.00	

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NCEP15P30A

Electrical Characteristics (Tc=25 $^{\circ}$ C unless otherwise noted)

$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$	-250μA -1.2 I _D =-15A - I _D =-15A -	-1.7 83 92 30	- -1 ±100 -2.5 100 110	V μA nA V mΩ mΩ
Zero Gate Voltage Drain Current I_{DSS} V_{DS} =-150V I_{GSS} V_{DS} =-150V I_{GSS} V_{DS} =-150V I_{GSS} V_{DS} =±20V I_{GSS} V_{GS} =±20V I_{GSS} V_{DS} =±20V I_{GSS} V_{DS} =0 I_{DSS} V_{DS} =-10V, V_{DS} =-10V, V_{DS} =-10V, V_{DS} =-5V, I_{DSS} I_{DSS} =-5V, I_{DSS} =-75V, $I_$	-250μA -1.2 I _D =-15A - I _D =-15A -	-1.7 83 92	-1 ±100 -2.5 100 110	μΑ nA V mΩ
$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$	-250μA -1.2 I _D =-15A - , I _D =-15A -	-1.7 83 92	±100 -2.5 100 110	nA V mΩ
	=-250μA -1.2 I _D =-15A - , I _D =-15A -	-1.7 83 92	-2.5 100 110	V mΩ mΩ
$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$	I _D =-15A	83	100 110	mΩ mΩ
$ \begin{array}{c} & V_{GS} \!\!=\!\! -10V, \\ \hline V_{GS} \!\!=\!\! -4.5V \\ \hline Forward Transconductance & g_{FS} & V_{DS} \!\!=\!\! -5V, \\ \hline \textbf{Dynamic Characteristics} \\ \hline Input Capacitance & C_{Iss} \\ \hline Output Capacitance & C_{oss} \\ \hline Reverse Transfer Capacitance & C_{rss} \\ \hline \textbf{Switching Characteristics} \end{tabular} $	I _D =-15A	83	100 110	mΩ mΩ
$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$, I _D =-15A -	92	110	mΩ
Forward Transconductance g_{FS} V_{DS} =-5V, Dynamic Characteristics Input Capacitance C_{Iss} Output Capacitance C_{Oss} Reverse Transfer Capacitance C_{rss} Switching Characteristics (Note 2) Turn-on Delay Time $t_{d(on)}$ Turn-on Rise Time t_r V_{DD} =-50V	,	+		
	l _D =-15A -	30	-	S
		1		
$\begin{array}{c ccccccccccccccccccccccccccccccccccc$	_			
	.,	1650	-	PF
	· -	135	-	PF
	- IVITIZ	12	-	PF
Turn-on Rise Time t_r V_{DD} =-50V				
	-	10	-	nS
Turn-Off Delay Time t _{4/off} V _{cc} =-10V	,I _D =-15A -	18	-	nS
Tam on Boldy Time	R _G =1.6Ω -	20	-	nS
Turn-Off Fall Time t _f	-	15	-	nS
Total Gate Charge Q _g	-	25	-	nC
Gate-Source Charge Q_{gs} V_{DS} =-75V,	· -	5.2	-	nC
Gate-Drain Charge Q_{gd} V_{GS} =-	-	3.1	-	nC
Drain-Source Diode Characteristics	•			
Diode Forward Voltage V _{SD} V _{GS} =0V,I	s=-15A -		-1.2	V
Diode Forward Current Is	-	-	-30	Α
Reverse Recovery Time t_{rr} $T_J = 25^{\circ}C$,	I _F =-15A -	55	-	nS
Reverse Recovery Charge Qrr di/dt = 10	00A/μs -	101	-	nC

Notes:

- 1. EAS condition : Tj=25 $^{\circ}\text{C}$,VDD=-50V,VG=-10V,L=0.5mH,Rg=25 Ω
- 2. Guaranteed by design, not subject to production
- 3. These curves are based on the junction-to-case thermal impedance which is measured with the device mounted to a large heatsink, assuming a maximum junction temperature of TJ(MAX)=175°C. The SOA curve provides a single pulse rating.





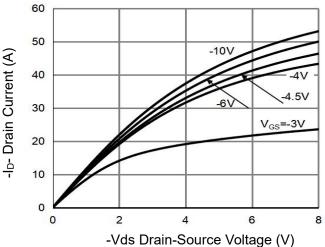


Figure 1 Output Characteristics

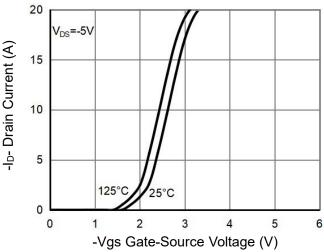


Figure 2 Transfer Characteristics

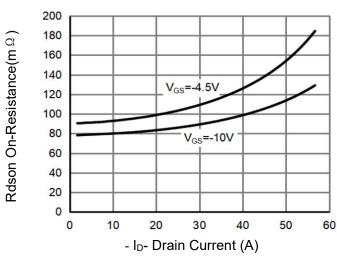


Figure 3 Rdson- Drain Current

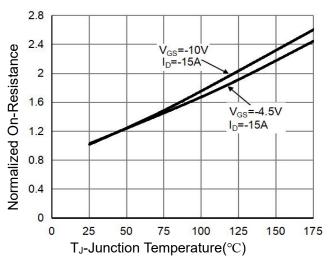


Figure 4 Rdson-JunctionTemperature

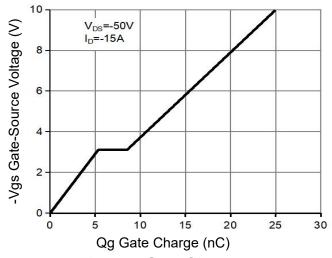


Figure 5 Gate Charge

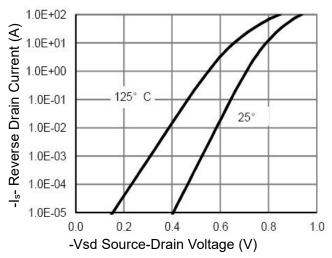


Figure 6 Source- Drain Diode Forward



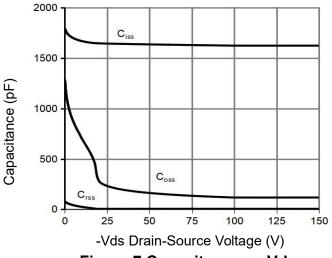


Figure 7 Capacitance vs Vds

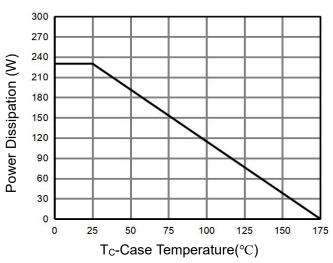


Figure 9 Power De-rating

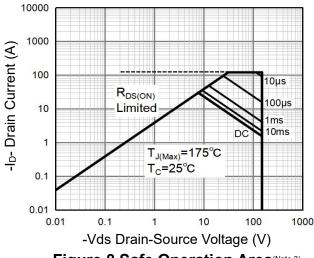


Figure 8 Safe Operation Area(Note 3)

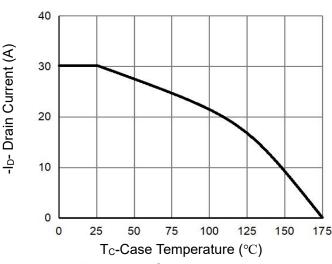


Figure 10 Current De-rating

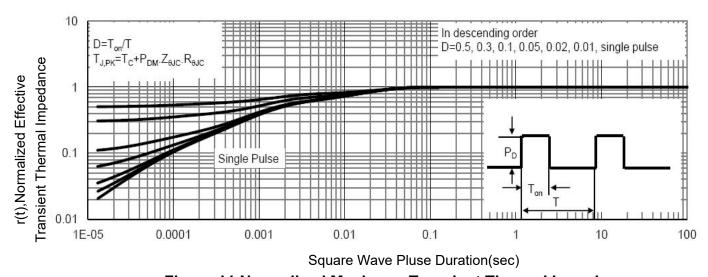
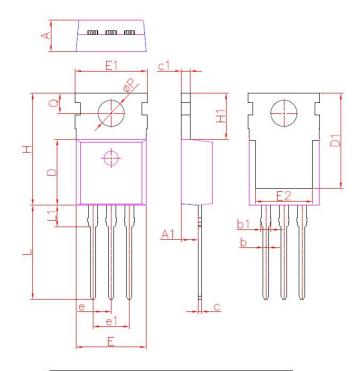


Figure 11 Normalized Maximum Transient Thermal Impedance



TO-220-3L Package Information



	10	220	Les construction
DIM.	MIN.	NOM.	MAX.
Α	4.20	4.40	4.60
A1	2.25	2,40	2.55
b	0.70	0.80	0.90
b1	1.17	1.27	1.37
С	0.33	0.50	0.65
c1	1.20	1.30	1.40
D	8.95	9.20	9.75
D1	13.10	13.30	13.50
Ε	9.74	9.84	10.04
E1	9.91	10.08	10.25
E2	7.90	8.00	8.10
е	2.54BSC		
e1	5.08BSC		
Н	15.45	15.65	15.85
H1	6.30	6.45	6.60
L	12.90	13.13	13.40
L1	2.85	3.05	3.25
Q	2.65	2.80	2.95
ØΡ	3.40	3.68	3.80

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NCEP15P30A

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